MSK5055RH, RAD HARD High Voltage Synchronous Switching Regulator Controller

> March 26, 2013 (First HDR TID, WAFER LOT: WD005797WF#9) March 26, 2013 (Neutron Irradiation, WAFER LOT: WD005797WF#9) March 20, 2018 (2nd HDR TID, WAFER LOT: W1621790.1WF#8) March 21, 2018 (3rd HDR TID, WAFER LOT: W1535549.1WF#9) May 24, 2018 (4th HDR TID, WAFER LOT: WP63227E.1WF#4)

> > N. Kresse F. Freytag

Anaren, Inc – MSK Products

The Total Ionizing Dose radiation test plan for the MSK5055RH was developed to qualify the devices as RAD Hard to 300Krad(Si). The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5055-1RH, and MSK5055-2RH both use the same active components. The data in this report is from direct measurement of the MSK5055-1RH response to irradiation but it is indicative of the response of both devices and is applicable to both.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5055RH.

II. Radiation Source:

Total ionizing dose testing was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 121.3 rad(Si)/sec. The total dose schedule can be found in Table I.

III. <u>Test Setup</u>:

All test samples were subjected to Group A Electrical Test in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015 and were fully screened IAW MIL-PRF-38535 Class H. For test platform verification, two control devices were tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and the devices were transported to the electrical test platform. Testing was performed in accordance with the MSK device data sheet. Testing was performed on irradiated devices, as well as the control devices, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices respectively. Post 300Krad(Si) limits have also been plotted for reference. If required, full test data can be obtained by contacting Anaren, Inc – MSK Products.

V. <u>Summary</u>:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5055RH qualifies as a 300Krad(Si) radiation hardened devices. Error Amp Reference Voltage, Vin UVLO Threshold (Rising), Operating Frequency, and Current Limit Sense Voltage exhibited the most significant shifts with irradiation. These parameters stayed well within specified post irradiation limits at 100Krad(Si) and 300krad(Si). All other parameters stayed within pre-irradiation specifications 300Krad(Si).

MSK5055-1RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment	
Bruker Biospin # 0162	

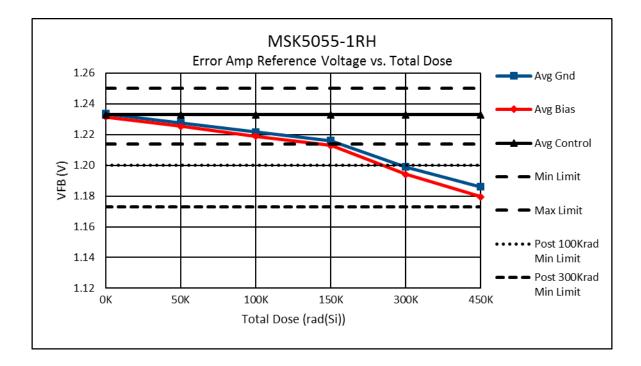
Irradiation Date	
5/24/18	

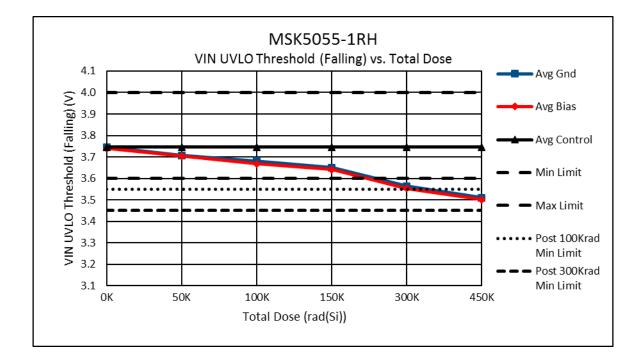
Exposure Length (min:sec)	Incremental Dose rad(Si)	Cumulative Dose rad(Si)
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7:05	51,500	103,000
7:05	51,500	154,500
21:14	154.500	309,000
21:14	154,500	463,500

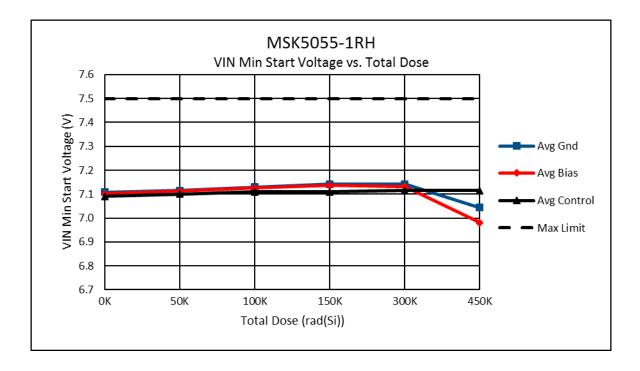
Biased S/N – 0013, 0014, 0015, 0017, 00	18

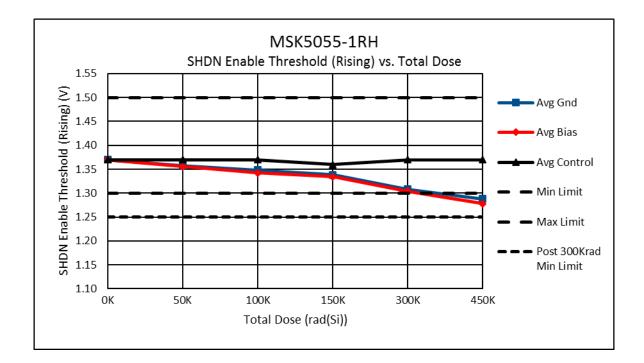
Unbiased S/N – 0020, 0021, 0022, 0023, 0	0024
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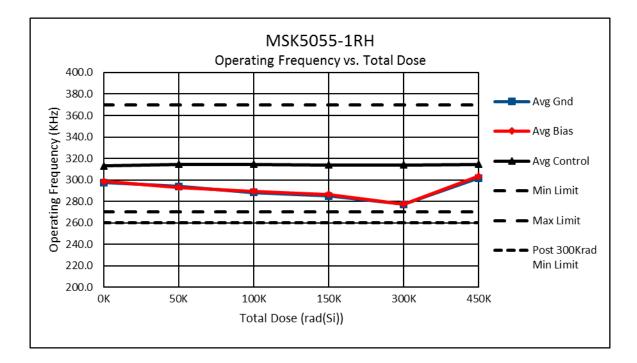
Table 1

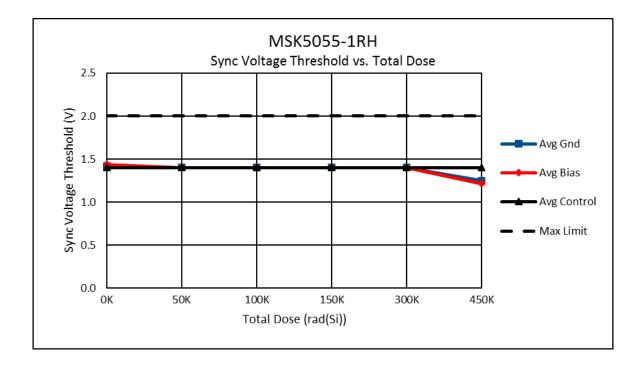


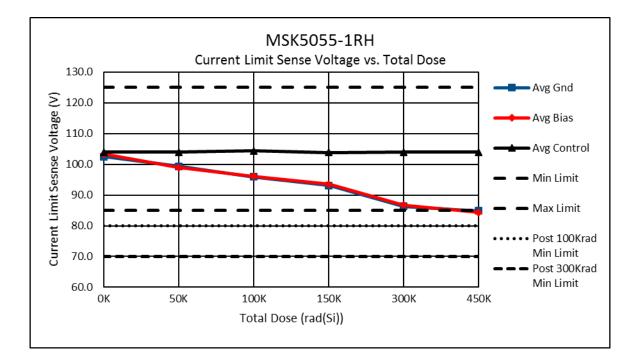


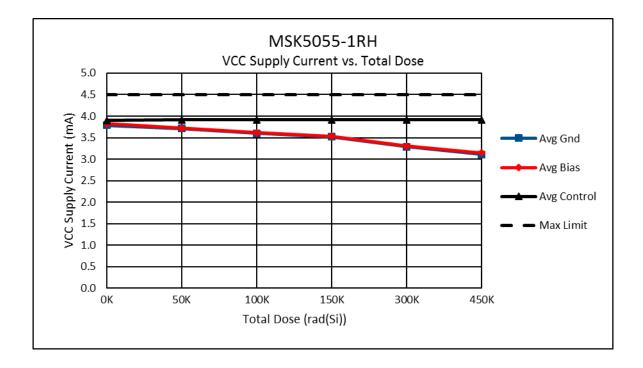


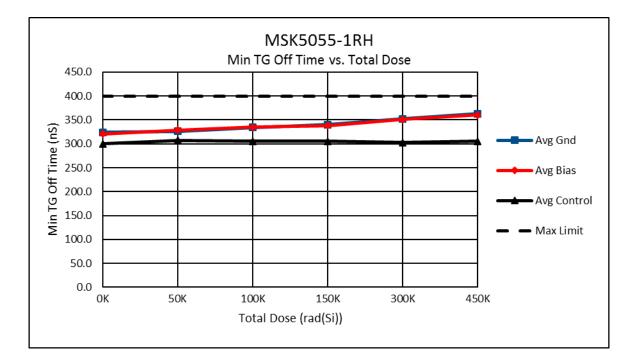


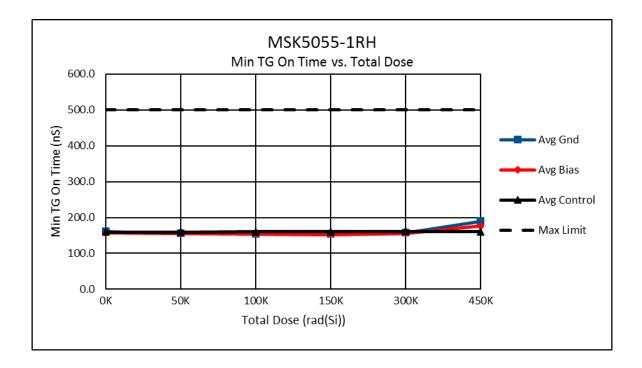


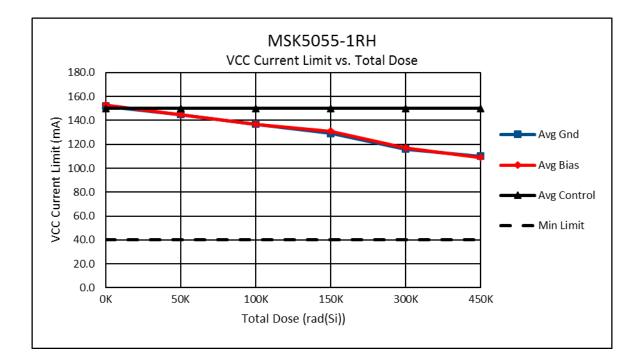












MSK5055RH, RAD HARD High Voltage Synchronous Switching Regulator Controller

March 26, 2013 (First HDR TID, WAFER LOT: WD005797WF#9) March 26, 2013 (Neutron Irradiation, WAFER LOT: WD005797WF#9) March 20, 2018 (2nd HDR TID, WAFER LOT: W1621790.1WF#8) March 21, 2018 (3rd HDR TID, WAFER LOT: W1535549.1WF#9)

> B. Horton J. Joy

Anaren, Inc – MSK Products

The Total Ionizing Dose radiation test plan for the MSK5055RH was developed to qualify the devices as RAD Hard to 300krad(Si). The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5055-1RH, and MSK5055-2RH both use the same active components. The data in this report is from direct measurement of the MSK5055-1RH response to irradiation but it is indicative of the response of both devices and is applicable to both.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5055RH.

II. Radiation Source:

Total ionizing dose testing was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 124 rad(Si)/sec. The total dose schedule can be found in Table I.

III. <u>Test Setup</u>:

All test samples were subjected to Group A Electrical Test in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015 and were fully screened IAW MIL-PRF-38535 Class H. For test platform verification, one control device was tested at 25°C. Nine devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Four devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and the devices were transported to the electrical test platform. Testing was performed in accordance with the MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices respectively. Post 300krad(Si) limits have also been plotted for reference. If required, full test data can be obtained by contacting Anaren, Inc – MSK Products.

V. <u>Summary</u>:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5055RH qualifies as a 300krad(Si) radiation hardened devices. The parameter VIN MIN START VOLTAGE test was not properly executed and has been exclude from this report. Future test effort will include this parameter. Error Amp Reference Voltage, Vin UVLO Threshold (Rising), Operating Frequency, and Current Limit Sense Voltage exhibited the most significant shifts with irradiation. These parameters stayed well within specified post irradiation limits at 100krad(Si) and 300krad(Si). All other parameters stayed within pre-irradiation specifications 300krad(Si).

MSK5055-1RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment	
Bruker Biospin # 0162	

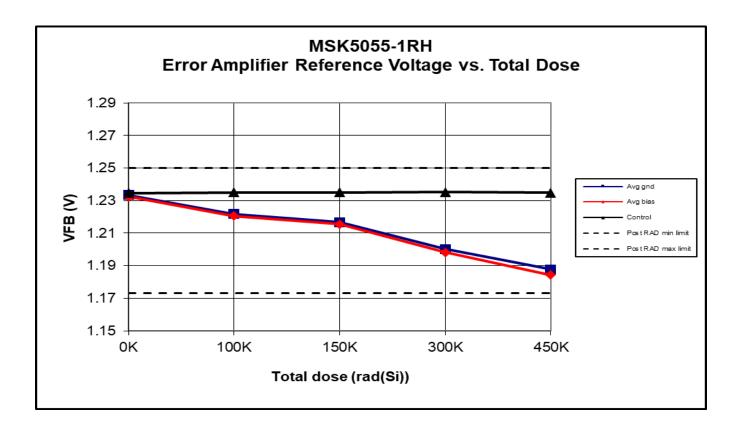
Irradiation Date
3/21/18

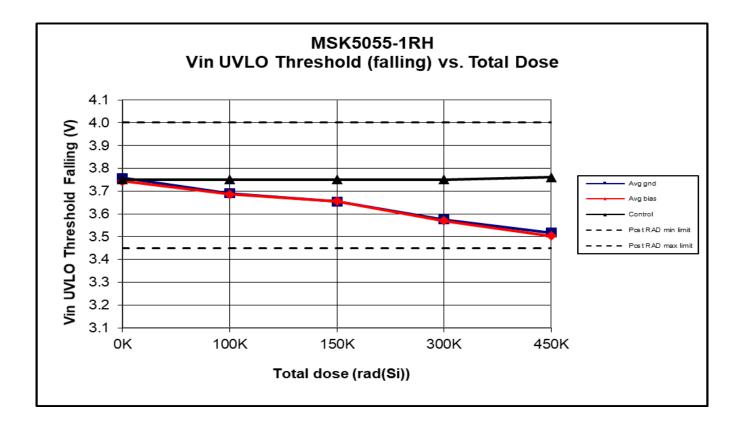
Exposure Length (min:sec)	Incremental Dose rad(Si)	Cumulative Dose rad(Si)
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6:55	51,500	154,500
20:46	154,500	309,000
20:46	154,500	463,500

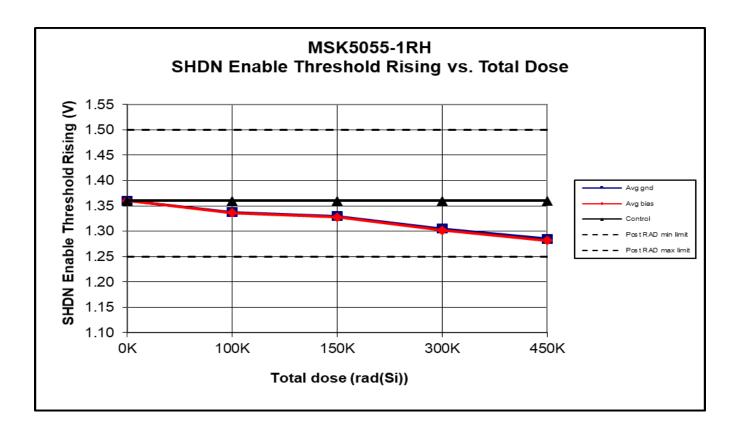
Biased S/N – 0001, 0002, 0003, 0004,
0005

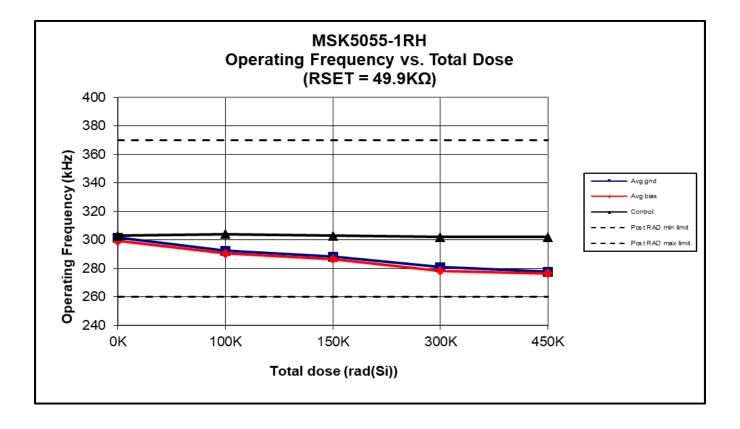
Unbiased S/N – 0006, 0007, 0008, 0011

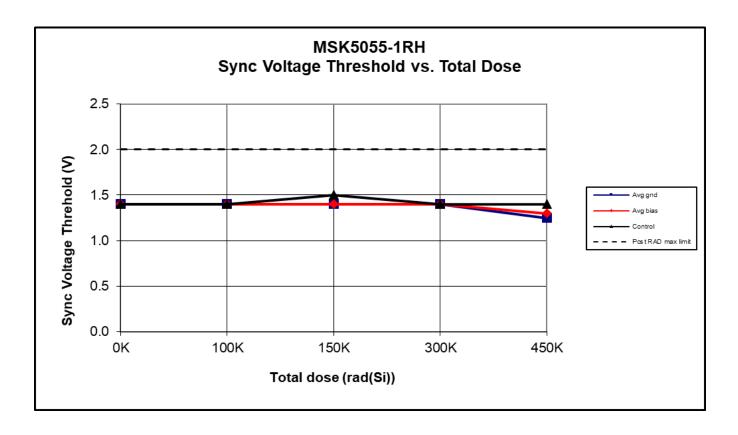
Table 1

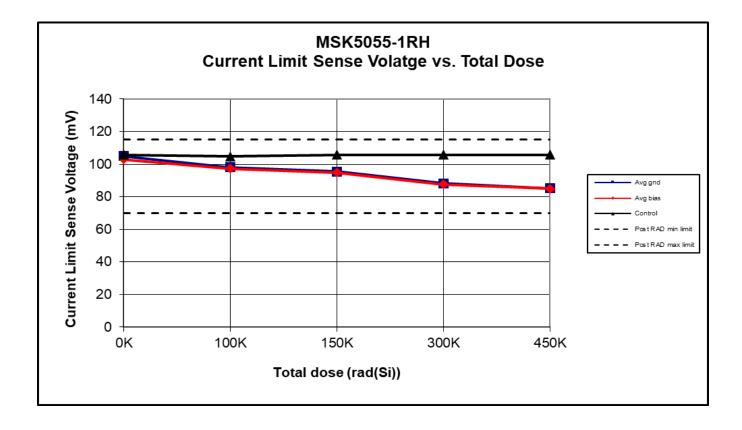


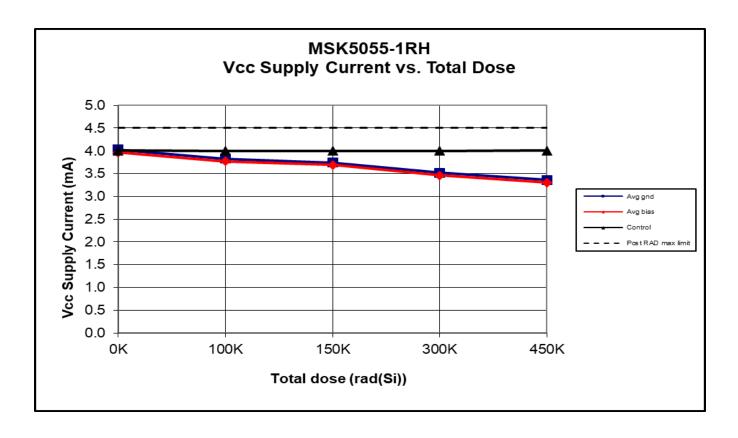


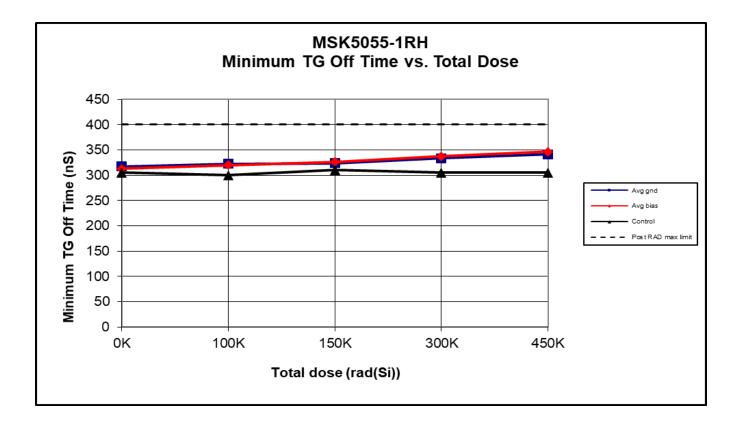


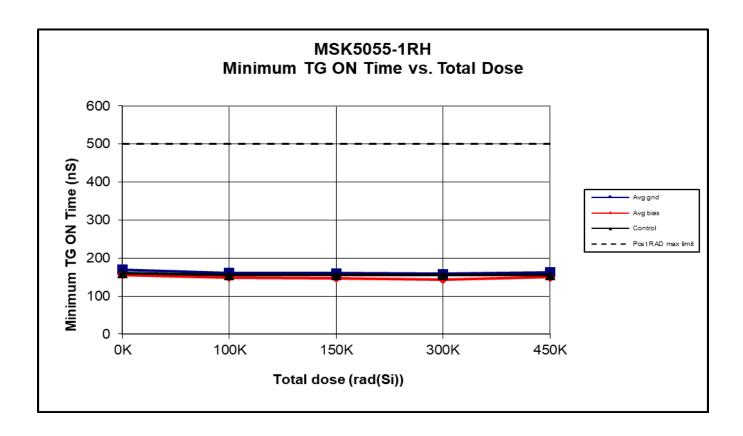


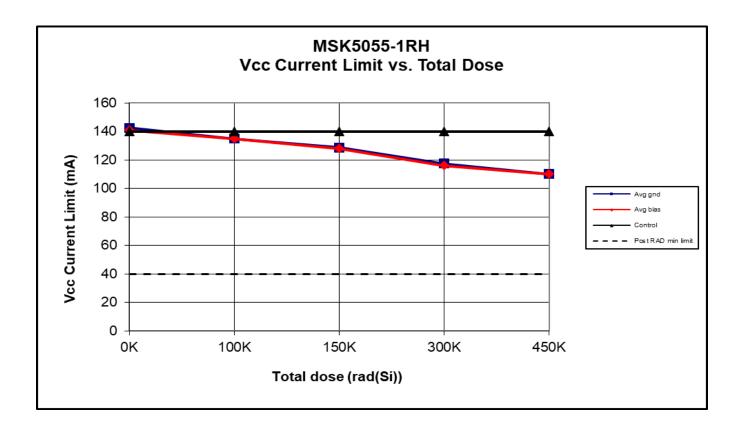












MSK5055RH, RAD HARD High Voltage Synchronous Switching Regulator Controller

March 26, 2013 (First HDR TID, WAFER LOT: WD005797WF#9) March 26, 2013 (Neutron Irradiation, WAFER LOT: WD005797WF#9) March 20, 2018 (2nd HDR TID, WAFER LOT: W1621790.1WF#8)

> B. Horton J. Joy

Anaren, Inc – MSK Products

The Total Ionizing Dose radiation test plan for the MSK5055RH was developed to qualify the devices as RAD Hard to 300krad(Si). The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5055-1RH, and MSK5055-2RH both use the same active components. The data in this report is from direct measurement of the MSK5055-1RH response to irradiation but it is indicative of the response of both devices and is applicable to both.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5055RH.

II. Radiation Source:

Total ionizing dose testing was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 124 rad(Si)/sec. The total dose schedule can be found in Table I.

III. <u>Test Setup</u>:

All test samples were subjected to Group A Electrical Test in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015 and were fully screened IAW MIL-PRF-38535 Class H. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and the devices were transported to the electrical test platform. Testing was performed in accordance with the MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices respectively. Post 300krad(Si) limits have also been plotted for reference. If required, full test data can be obtained by contacting Anaren, Inc – MSK Products.

V. <u>Summary</u>:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5055RH qualifies as a 300krad(Si) radiation hardened devices. The parameter VIN MIN START VOLTAGE test was not properly executed and has been exclude from this report. Future test effort will include this parameter. Error Amp Reference Voltage, Vin UVLO Threshold (Rising), Operating Frequency, and Current Limit Sense Voltage exhibited the most significant shifts with irradiation. These parameters stayed well within specified post irradiation limits at 100krad(Si) and 300krad(Si). All other parameters stayed within pre-irradiation specifications 300krad(Si).

MSK5055-1RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment	
Bruker Biospin # 0162	

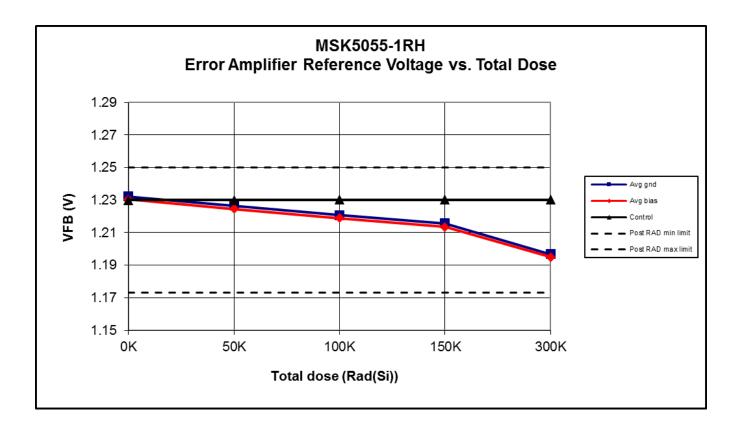
Irradiation Date	
3/20/18	

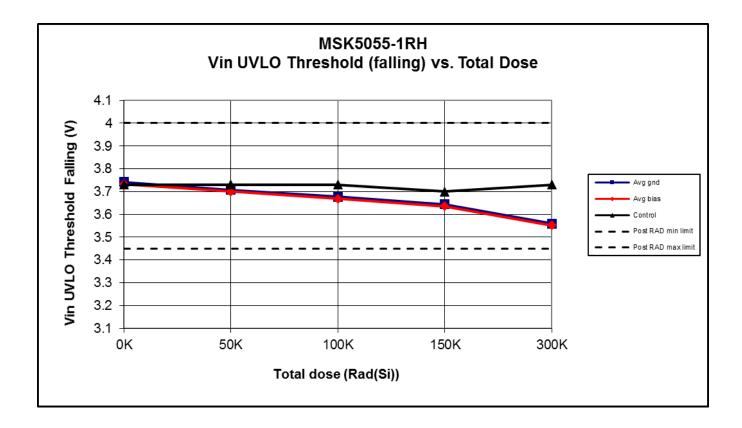
Exposure Length (min:sec)	Incremental Dose rad(Si)	Cumulative Dose rad(Si)
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06:55	51,500	103,000
06:55	51,500	154,500
20:46	154,500	309,000

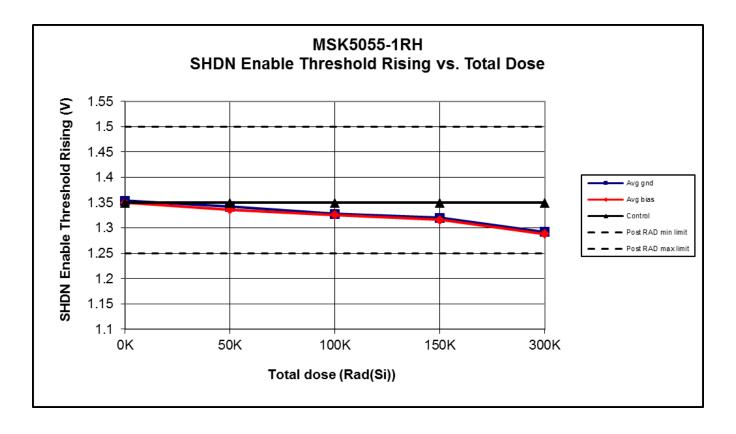
Biased S/N – 0674, 0675, 0676, 0677, 0)678

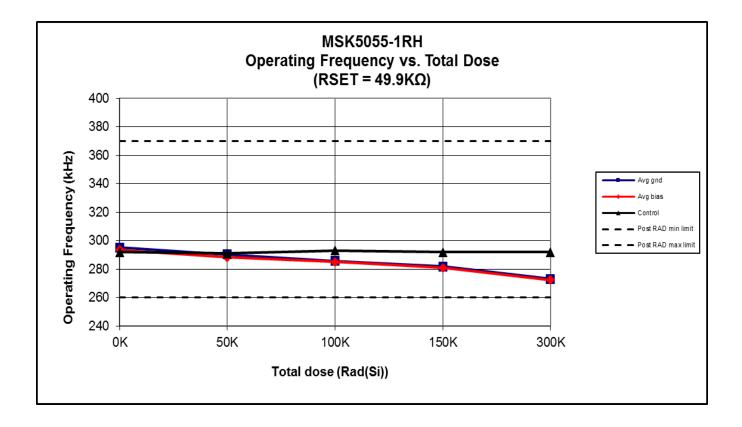
Unbiased S/N – 0679,	0680 0681	0682 0683
01010360 0/10 - 0073	0000, 0001,	0002,0005

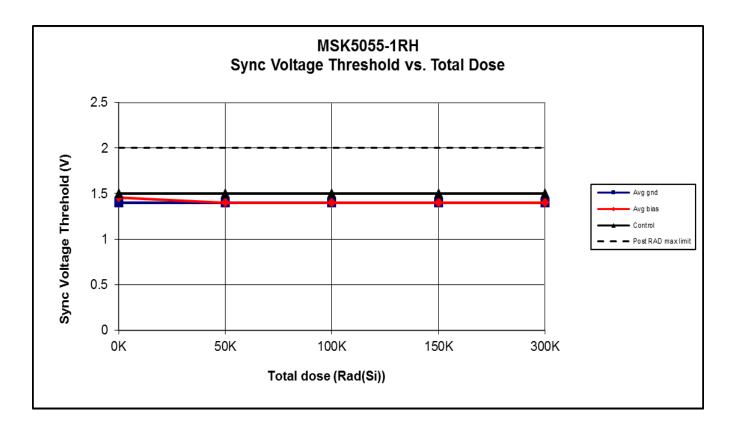
Table 1

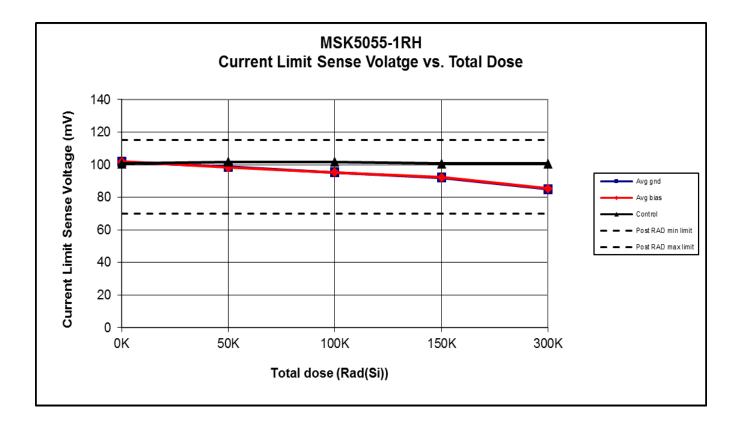


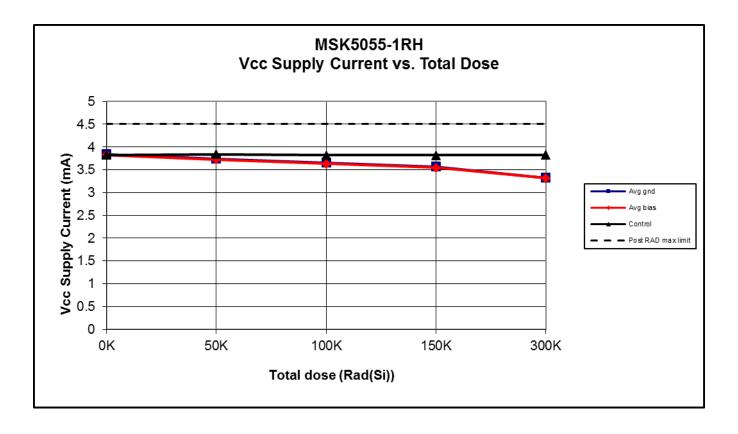


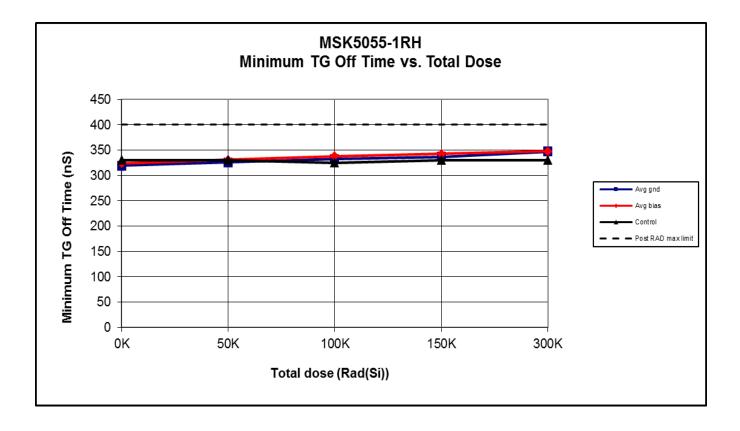


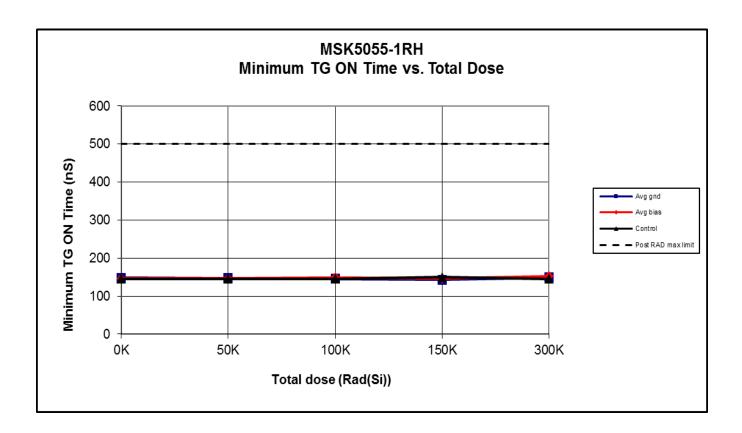


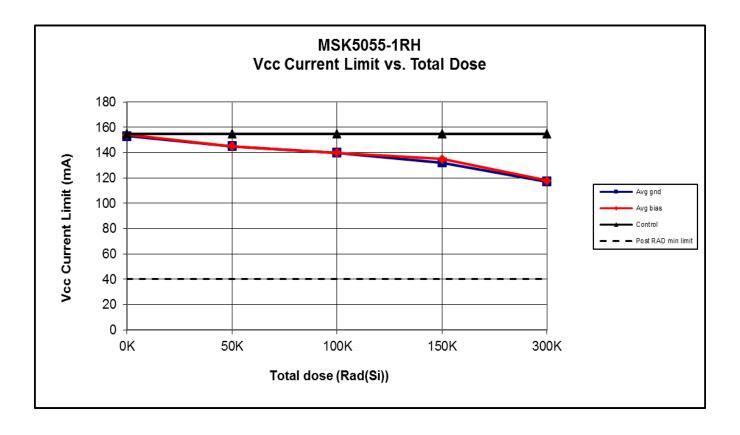












Neutron and Total Ionizing Dose Radiation Test Report

MSK5055RH, RAD HARD High Voltage Synchronous Switching Regulator Controller

March 26, 2013 (TID, WAFER LOT: WD005797WF#9) March 26, 2013 (Neutron Irradiation, WAFER LOT: WD005797WF#9)

> B. Horton R. Wakeman

M.S. Kennedy Corporation Liverpool, NY

The Neutron Irradiation test for the MSK5055RH was performed to determine the change in device performance as a function of neutron fluence. The testing was performed to 5.38 x 10¹¹ n/cm² total integral fluence. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the indicated fluence levels. The MSK5055RH-1 and MSK5055RH-2 use the same active component. The data herein is from direct measurement of the MSK5055RH-1 response to neutron irradiation, but is indicative of the response of both device types.

MIL-STD-883 Method 1017.9 was used as the basis in the development and implementation of the Neutron Irradiation test plan for the MSK5055RH series.

II. Radiation Source:

Neutron Irradiation was performed at the University of Massachusetts, Lowell, using the Reactor Facility-FNI. The neutron flux was determined by dosimetry system S/P-32, method ASTM E-265, to be 4.05×10^8 n/cm²-S (1 MeV equivalent) for each irradiation step.

III. <u>Test Setup</u>:

All test samples were subjected to Group A Electrical Test in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015 and were fully screened I.A.W. MIL-PRF-38534 Class K. For test platform verification, one control device was tested at 25°C. Five devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

During irradiation, devices leads were shorted together using antistatic foam and then devices were placed into an anti-static bag. Devices were then vertically aligned with the radiation source.

After each irradiation step, the devices were transported to the MSK electrical test platform. Testing was performed in accordance with the MSK5055RH data sheet. Electrical testing was performed on the irradiated devices, as well as the control device, at each fluence level. Electrical tests were completed within twenty four hours of irradiation.

IV. <u>Data</u>:

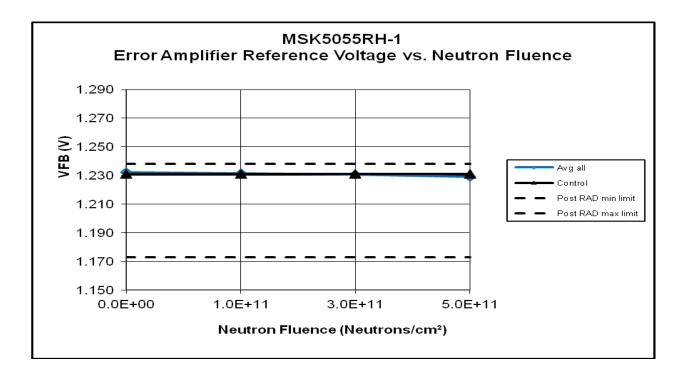
All performance curves are averaged from the test results of the irradiated devices. Post 300KRAD(Si) limits have also been plotted for reference only. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

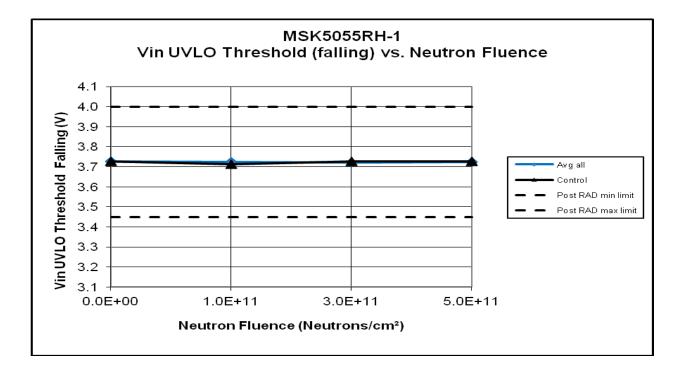
V. <u>Summary</u>:

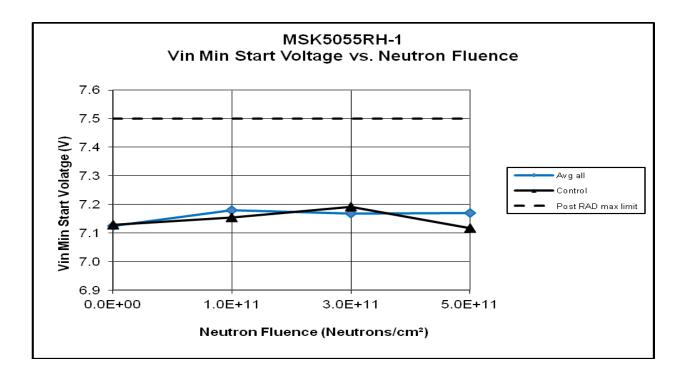
Based on data recorded during neutron irradiation testing and statistical analysis, the MSK5055RH series exhibits low susceptibility to neutron displacement damage. All devices performed well within data sheet specifications throughout all test intervals.

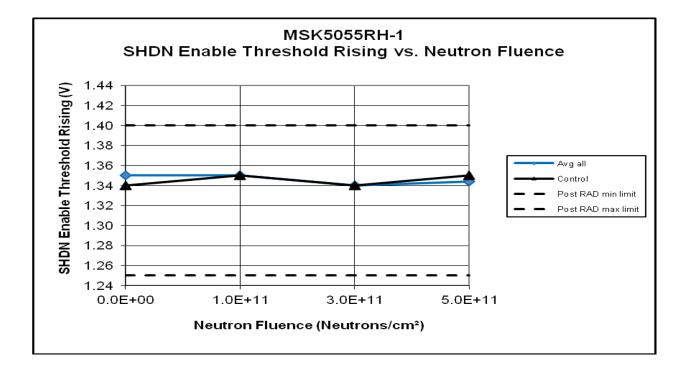
MSK5055RH Neutron Irradiation						
Reactor Facility – Fast Neutron Irradiation (FNI) Dosimetry System: S/P-32 (ASTM E-265)						
Exposure Date: 3/26/13						
Irradiation	Reactor Power (kW)	Gamma Dose Rad (Si)	Flux (n/cm²-S)	Time(s)	Fluence (n/cm²)	Total Fluence (n/cm²)
Step 1	5	14	4.05E8	247	1.14E11	1.14E11
Step 2	5	28	4.05E8	494	2.14E11	3.28E11
Step 3	5	28	4.05E8	494	2.10E11	5.38E11

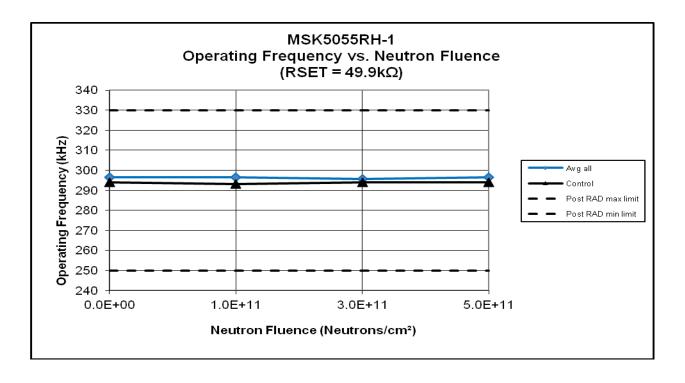
Gamma Dose, Neutron Flux and Total Fluence

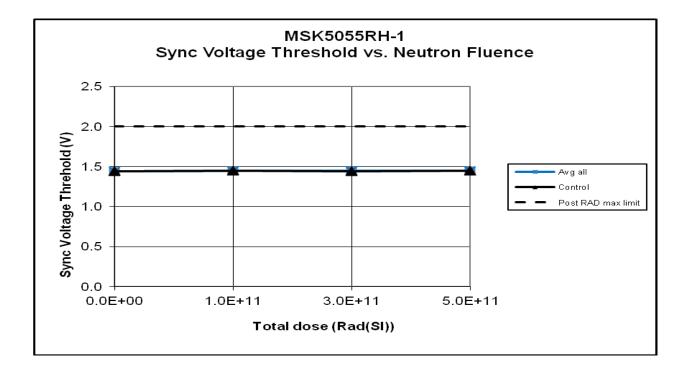


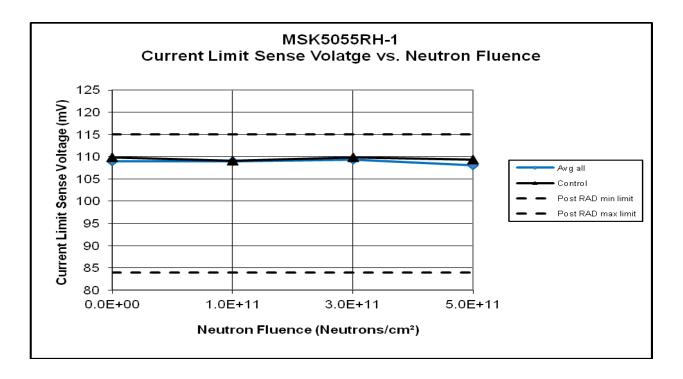


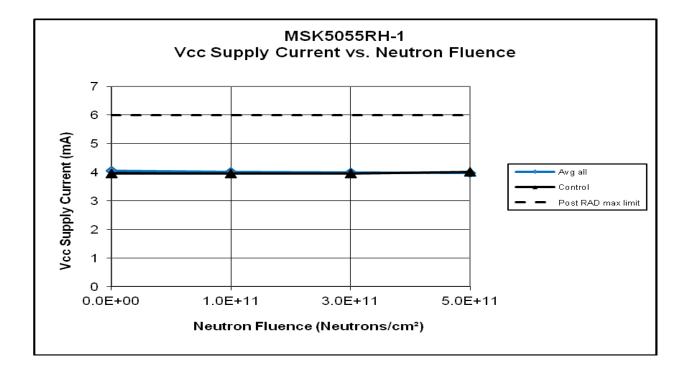


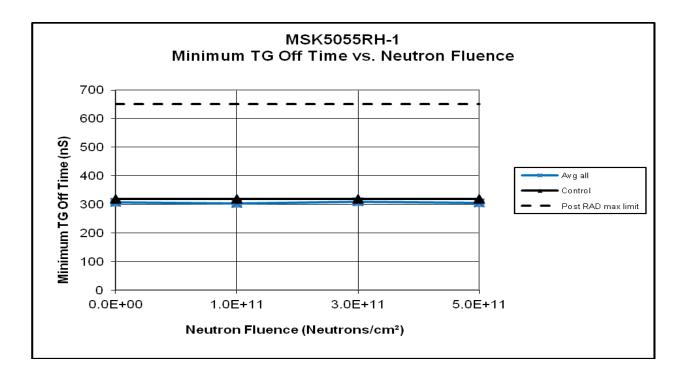


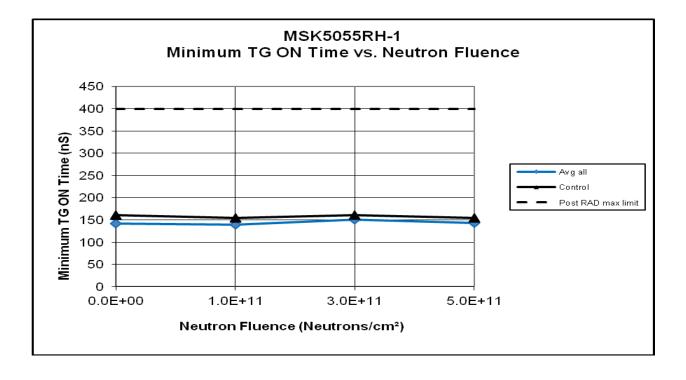


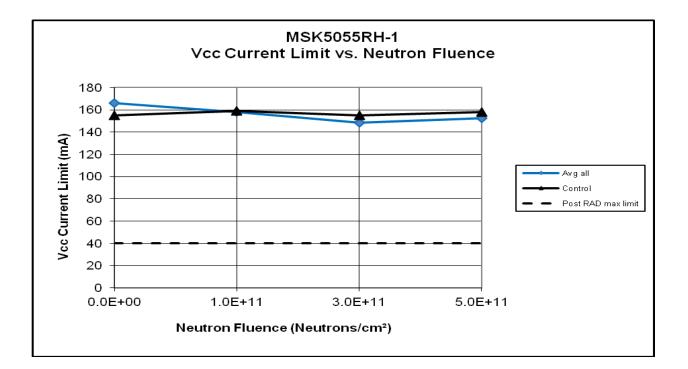












MSK5055RH, RAD HARD High Voltage Synchronous Switching Regulator Controller

March 26, 2013 (TID, WAFER LOT: WD005797WF#9)

B. Horton R. Wakeman

M.S. Kennedy Corporation Liverpool, NY

The Total Ionizing Dose radiation test plan for the MSK 5055RH was developed to qualify the devices as RAD Hard to 300KRADS(Si). Testing was performed beyond 300 KRADS(Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5055RH-1, and MSK5055RH-2 both use the same active components. The data in this report is from direct measurement of the MSK5055RH-1 response to irradiation but it is indicative of the response of both devices and is applicable to both.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5055RH.

II. Radiation Source:

Total ionizing dose testing was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 97 Rads(Si)/sec. The total dose schedule can be found in Table I.

III. <u>Test Setup</u>:

All test samples were subjected to Group A Electrical Test in accordance with the device data sheet. In addition, all devices received 240 hours of burn-in per MIL-STD-883 Method 1015 and were fully screened IAW MIL-PRF-38535 Class K. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and the devices were transported to the MSK electrical test platform. Testing was performed in accordance with the MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

IV. Data:

All performance curves are averaged from the test results of the biased and unbiased devices respectively. Post 300KRAD(Si) limits have also been plotted for reference. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

V. <u>Summary</u>:

Based on the test data recorded during radiation testing and statistical analysis, the MSK5055RH qualifies as 300 KRad(Si) radiation hardened devices. Error Amplifier Reference Voltage, Vin UVLO Threshold (falling), Operating Frequency, and Current Limit Sense Voltage exhibited the most significant shifts with irradiation. These parameters stayed within specified post irradiation limits at 100KRad(Si) and 300KRad(si). All other parameters stayed within pre-irradiation specifications up to or beyond 300KRad(Si).

MSK5055RH Biased/Unbiased Dose Rate Schedule

Dosimetry Equipment

Bruker Biospin # 0162

Irradiation Date	
3/27/13	

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
08:51	51,507	51,507
08:51	51,507	103,014
08:51	51,507	154,521
26:33	154,521	309,042
26:33	154,521	463,563

Biased S/N – 0012, 0013, 0014, 0015, 0016

Unbiased S/N - 0017, 0018, 0020, 0022, 0023

Table 1

